

Applications

- Repeaters
- Mobile Infrastructure
- LTE / WCDMA / CDMA / GSM
- General Purpose Wireless
- TDD or FDD systems
- Military Communications

Product Features

- Frequency Range: 0.05 – 4.0 GHz
- NF: 0.8 dB (@ 1.9 GHz)
- Output IP3: +37 dBm (@ 1.9 GHz, 4 dBm/tone Pout)
- P1dB: +23 dBm (@ 1.9 GHz)
- Small Signal Gain: 16 dB (@ 1.9 GHz)
- +5V Single Supply, 115 mA Current
- Chip Dimensions: 1.49 x 0.85 x 0.085 mm

General Description

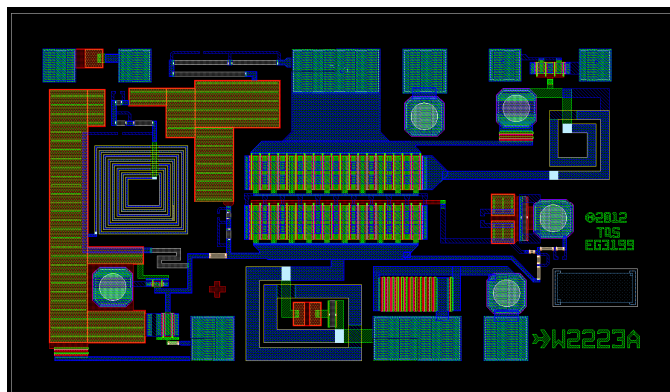
The TriQuint TGA4935 is a high linearity Low Noise Amplifier. The amplifier is fabricated using TriQuint's TQPED process. It is internally matched and only requires an external RF choke and blocking/bypass capacitors for operation from a single +5V supply. The internal active bias circuit also enables stable operation over bias and temperature variations.

The TGA4935 covers the 0.05–4.0 GHz frequency band and is targeted for wireless infrastructure or other applications requiring high linearity and/or low noise figure.

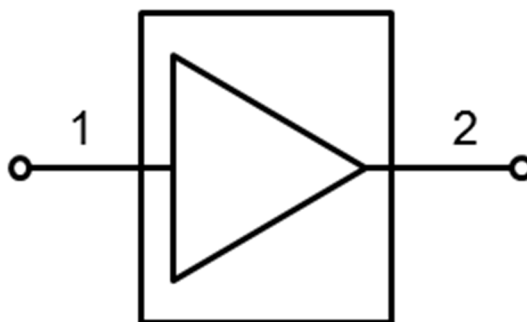
Die attach should be accomplished with conductive epoxy only. Eutectic attach is not recommended.

Lead-free and RoHS compliant

Evaluation Boards are available upon request.



Functional Block Diagram



Pad Configuration

Pad No.	Symbol
1	RF Input
2	RF Output/Bias

Ordering Information

Part	ECCN	Description
TGA4935	EAR99	High Linearity LNA Gain Block

Absolute Maximum Ratings

Parameter	Value
Drain Voltage (V_D)	7.0 V
Power Dissipation, 85 °C (P_{DISS})	1.2 W
Input Power, CW, 50 Ω , $T=25^\circ\text{C}$ (P_{IN})	23 dBm
Storage Temperature	-55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

Parameter	Value
Drain Voltage (V_D)	5 V
Drain Current (I_{DQ})	115 mA

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all operating conditions.

Electrical Specifications

Test conditions unless otherwise noted: 25 °C, $V_D = 5$ V, tested using EVB application circuit shown on page 7

Parameter	Min	Typical	Max	Units
Operational Frequency Range	0.05	1.9	4.0	GHz
Small Signal Gain		16.0		dB
Input Return Loss		27		dB
Output Return Loss		11		dB
Noise Figure		0.8		dB
Output Power at 1 dB Gain Compression		23		dBm
Output IP3 ($P_{out}=4$ dBm/tone)		37		dBm
Gain Temperature Coefficient		-0.007		dB/°C
Noise Figure Temperature Coefficient		0.005		dB/°C

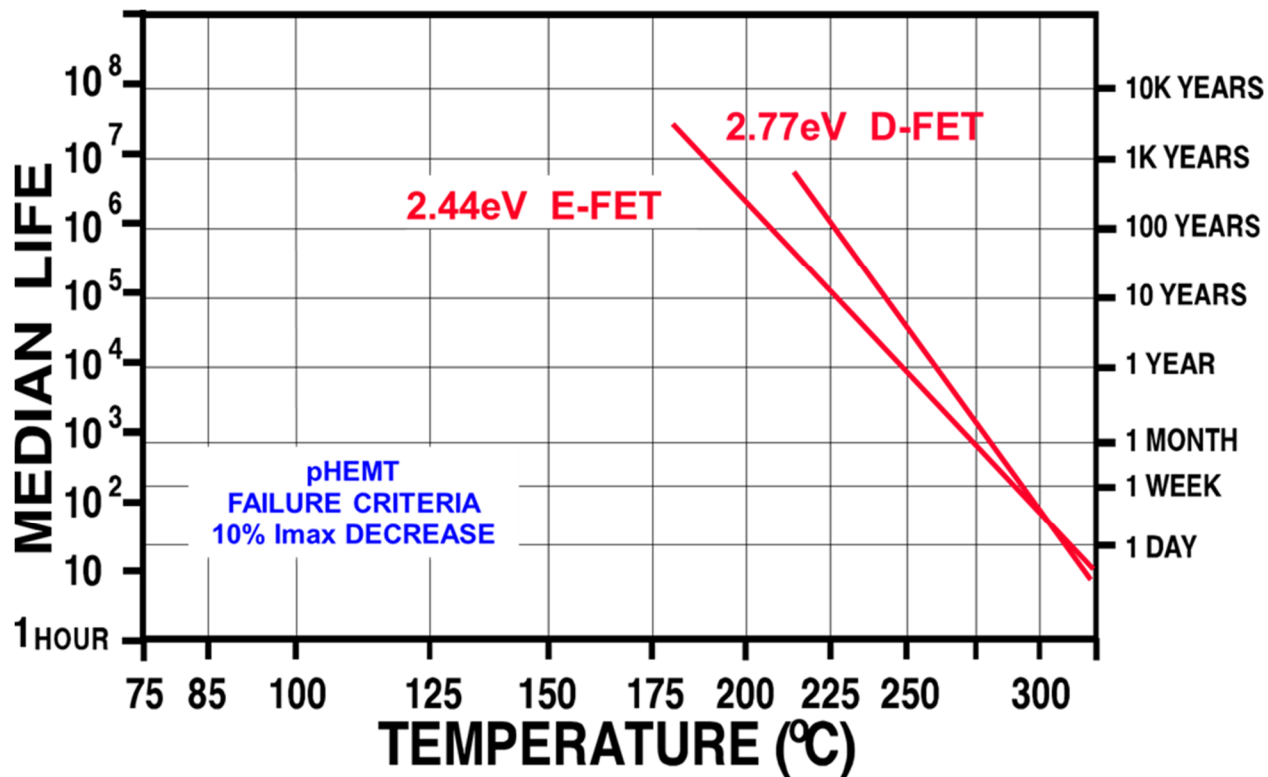
Thermal and Reliability Information

Parameter	Test Conditions	Value	Units
Thermal Resistance (θ_{JC}) ⁽¹⁾	$V_D = 5\text{ V}$, $I_{DQ} = 115\text{ mA}$, $P_{DISS} = 0.575\text{ W}$, $T_{base} = 85\text{ }^\circ\text{C}$	50	$^\circ\text{C/W}$
Channel Temperature (T_{CH})		114	$^\circ\text{C}$
Median Lifetime (T_M)		$>1.0\text{E}+7$	Hrs`

Notes:

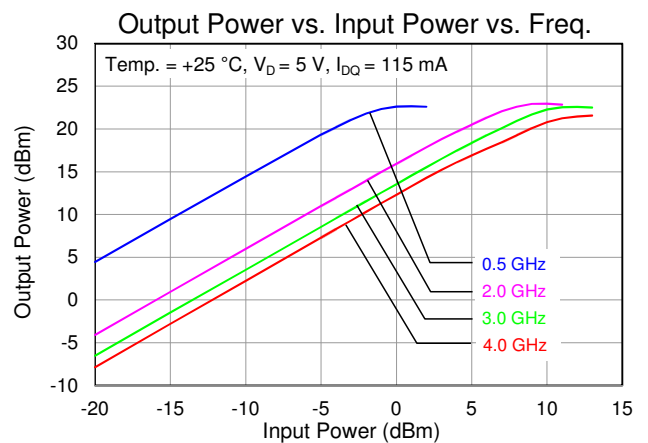
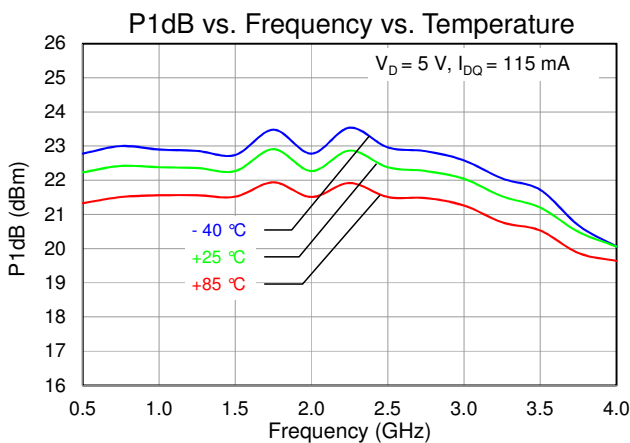
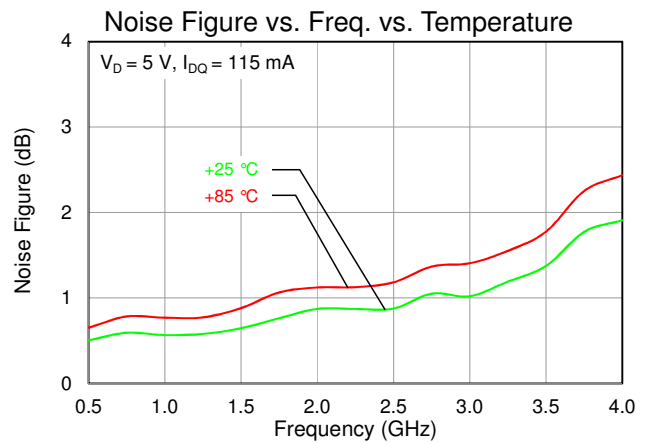
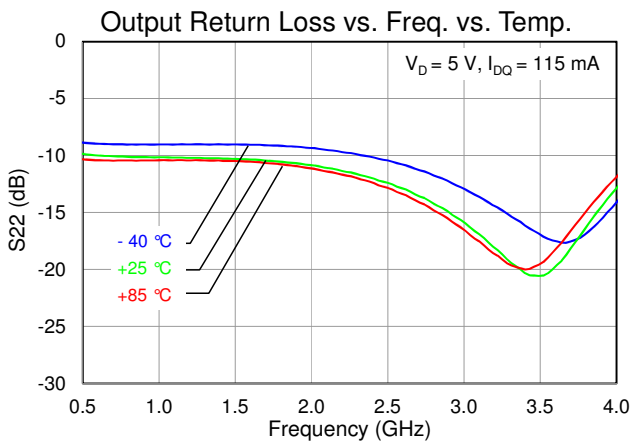
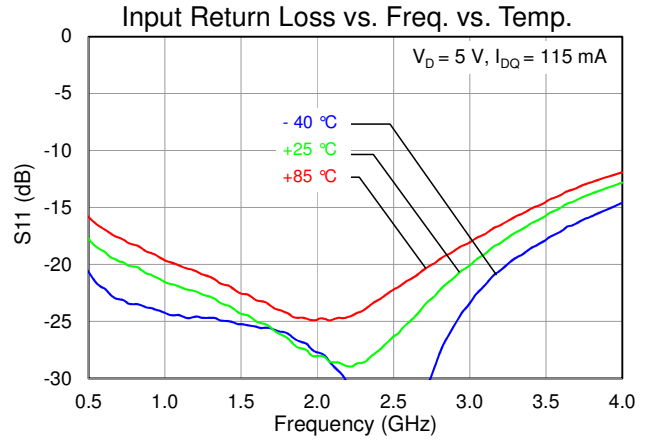
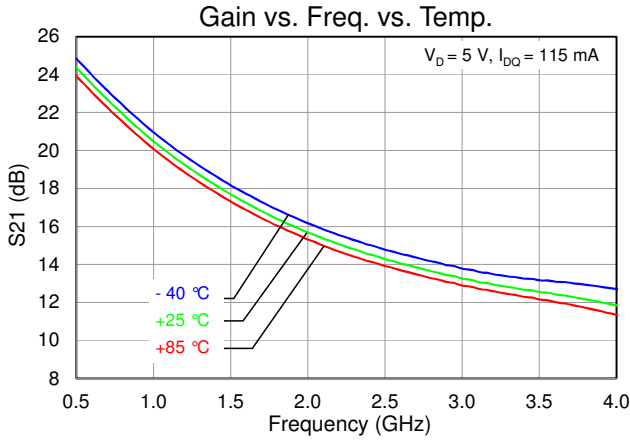
1. Thermal resistance measured to back of carrier plate. MMIC mounted on 8 mils thick CDA194 carrier using 84-1 epoxy.

Median Lifetime



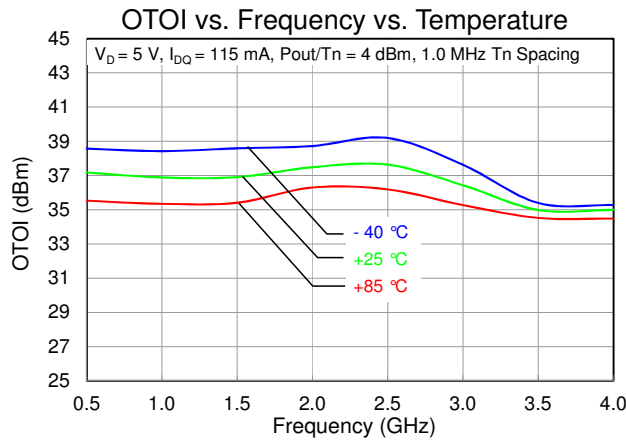
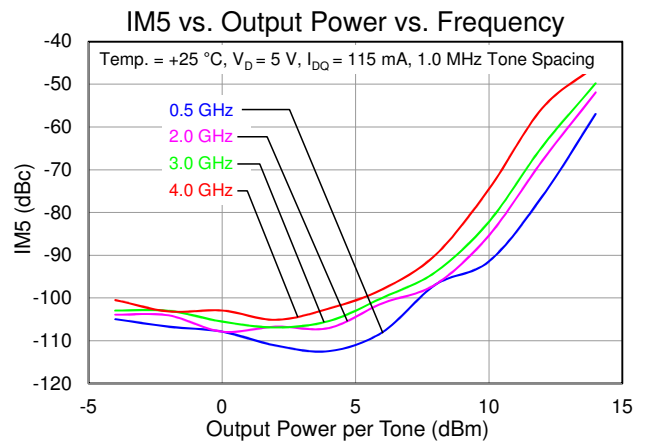
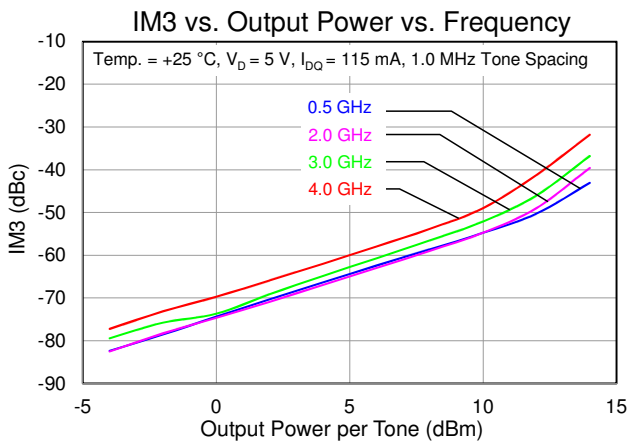
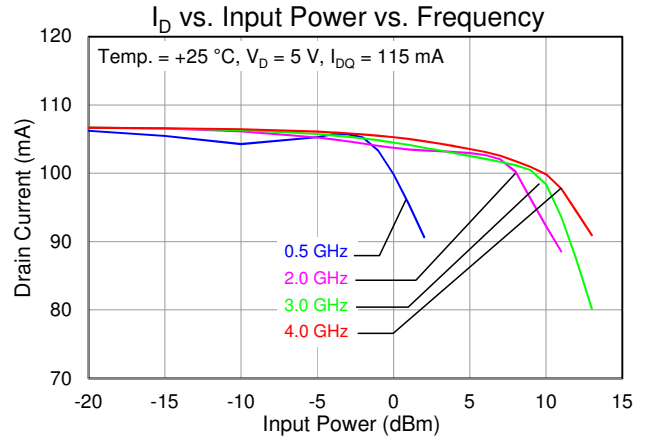
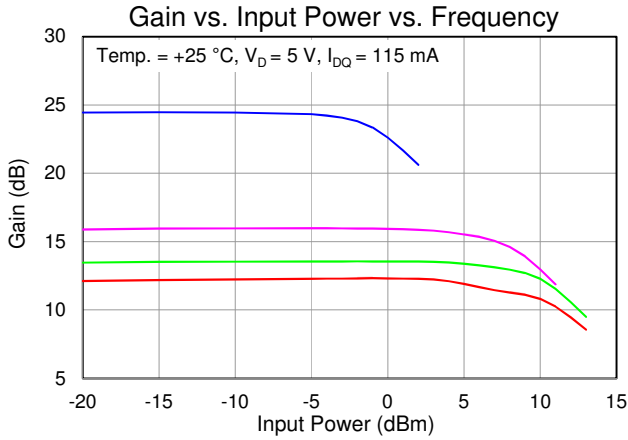
Typical Performance

Test conditions unless otherwise noted: 25 °C, $V_D = 5\text{ V}$, tested using EVB application circuit



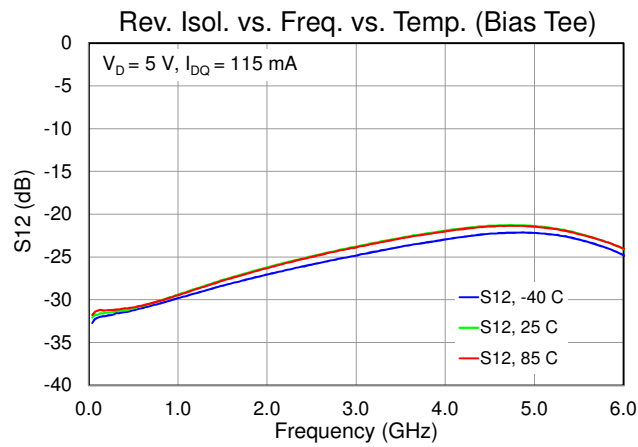
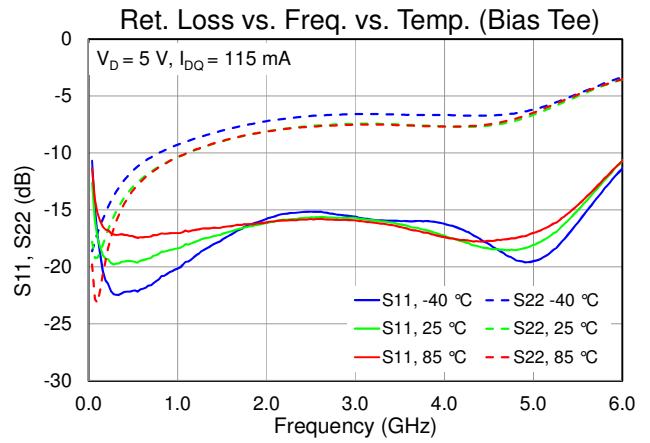
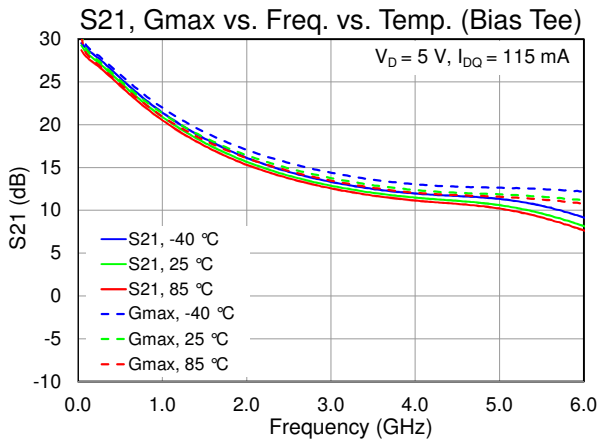
Typical Performance

Test conditions unless otherwise noted: 25 °C, $V_D = 5\text{ V}$, $I_{DQ} = 115\text{ mA}$, tested using EVB application circuit

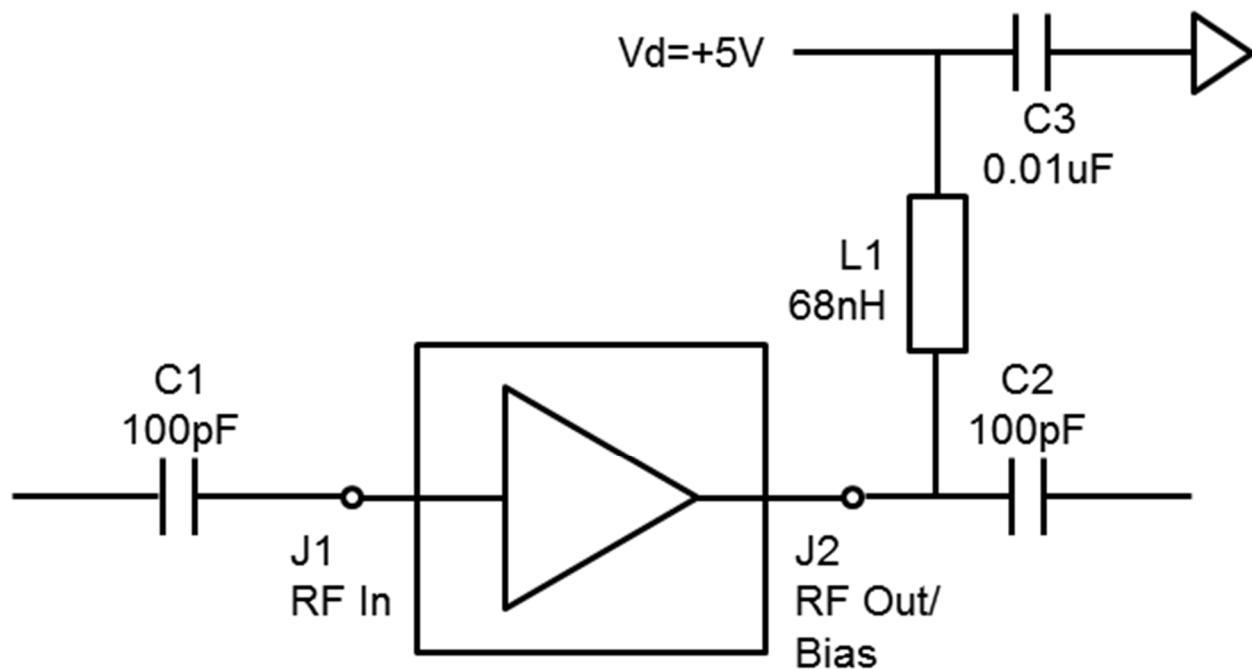


Typical Performance

Test conditions unless otherwise noted: 25 °C, $V_D = 5\text{ V}$, tested using external bias tees



Application Circuit



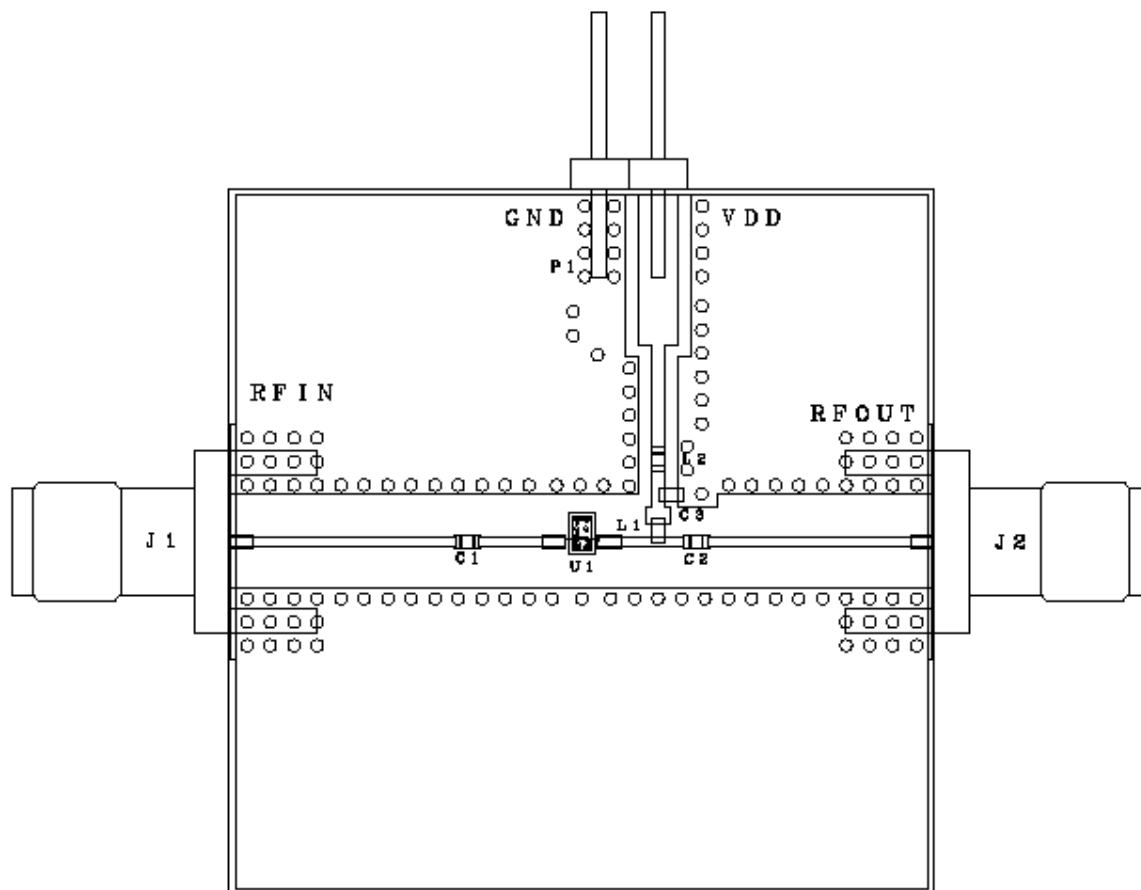
Bias-up Procedure

1. Set I_D limit to 170 mA, set V_D to 0 V
2. Apply +5 V to RF Output/Bias (part self-biases to appropriate I_{ds} value)
3. Apply RF signal

Bias-down Procedure

1. Turn off RF signal
2. Reduce V_D to 0 V
3. Turn off V_D supply

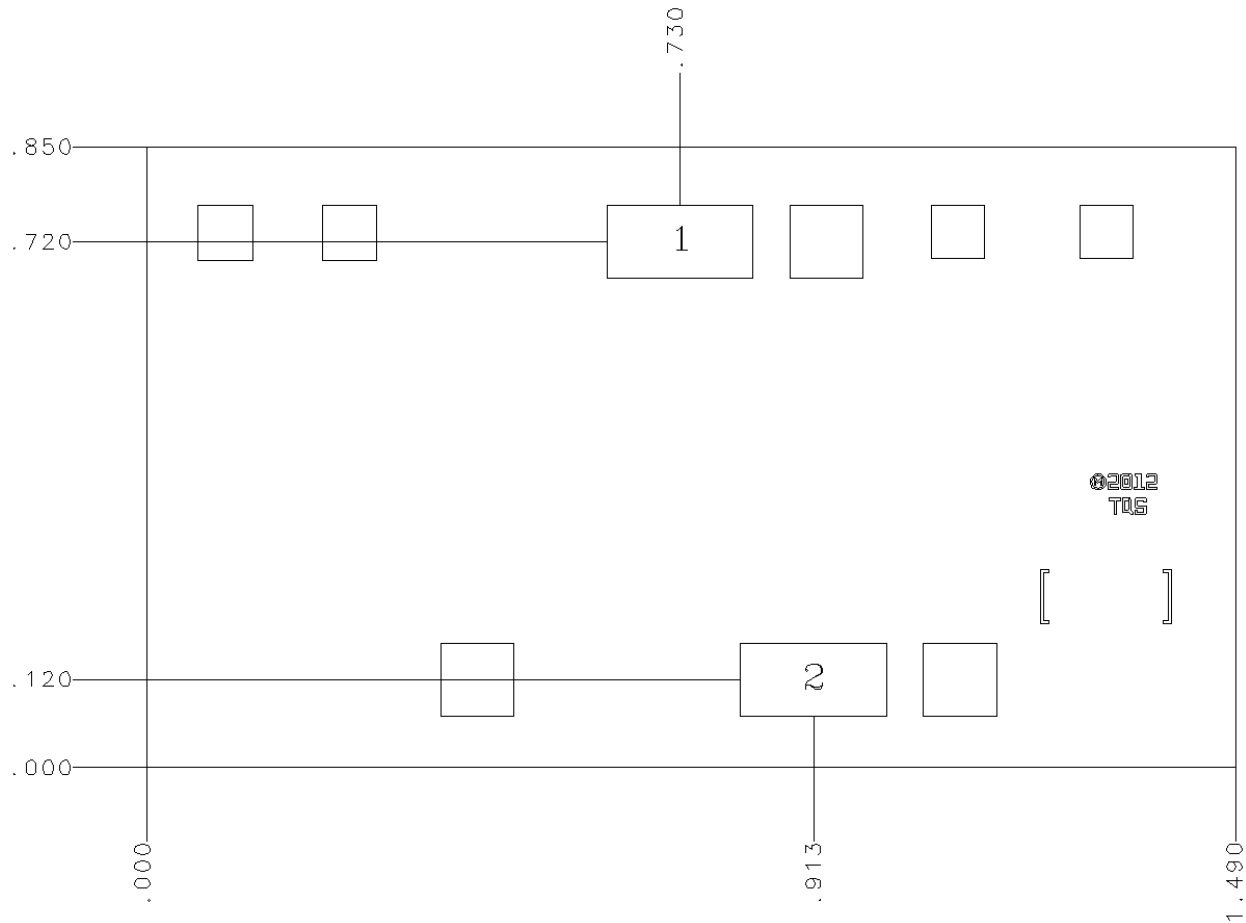
Assembly Drawing



Notes:

1. PCB material: Rogers 4003, 8 mil thick, 0.5 oz. copper.
2. RF Connector: Gigalane PSF-S01 SMA
3. 0402 Components: C1,C2=100pF, L1=68 nH coil, L2=0 Ohm Jumper, C3=0.01uF

Mechanical Drawing



Unit: millimeters
 Thickness: 0.085
 Die x, y size tolerance: +/- 0.050
 Chip edge to bond pad dimensions are shown to center of pad
 Ground is backside of die

Bond Pad	Symbol	Pad Size (mm)	Description
1	RF Input	0.150 x 0.100	RF Input, matched to 50 Ohms, not DC blocked
2	RF Output/Bias	0.150 x 0.100	RF Output, matched to 50 Ohms, not DC blocked, apply device bias

Assembly Notes

Component placement and adhesive attachment assembly notes:

- Vacuum pencils and/or vacuum collets are the preferred method of pick up.
- The force impact is critical during auto placement.
- Organic attachment (i.e. epoxy) can be used in low-power applications.
- Curing should be done in a convection oven; proper exhaust is a safety concern.

Interconnect process assembly notes:

- Thermosonic ball bonding is the preferred interconnect technique.
- Force, time, and ultrasonics are critical parameters.
- Aluminum wire should not be used.
- Devices with small pad sizes should be bonded with 0.0007-inch wire.

Product Compliance Information

ESD Sensitivity Ratings



Caution! ESD-Sensitive Device

ESD Rating: Class 1A
Value: Passes ≥ 250 V to < 500 V
Test: Human Body Model (HBM)
Standard: JEDEC Standard JESD22-A114

ECCN

US Department of Commerce: EAR99

Die Attach

Die attach should be accomplished with conductive epoxy only. Eutectic attach is not recommended.

RoHS Compliance

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

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